

DIRECT QUADRATURE MODULATOR

RF2484

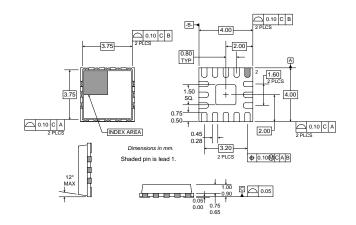
RoHS Compliant & Pb-Free Product

Typical Applications

- Dual-Band CDMA Base Stations
- TDMA/TDMA-EDGE Base Stations
- GSM-EDGE/EGSM Base Stations
- W-CDMA Base Stations
- WLAN and WLL Systems
- GMSK, QPSK, DQPSK, QAM Modulation

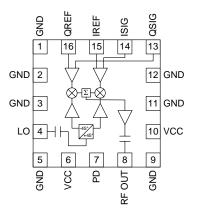
Product Description

The RF2484 is a monolithic integrated quadrature modulator IC capable of universal direct modulation for highfrequency AM, PM, or compound carriers. This low-cost IC features excellent linearity, noise floor, and over-temperature carrier suppression performance. The device implements differential amplifiers for the modulation inputs, 90° carrier phase shift network, carrier limiting amplifiers, two matched double-balanced mixers, summing amplifier, and an output RF amplifier which will drive 50 Ω from 800MHz to 2500MHz. It is packaged in a small industry-standard QFN 16-pin plastic package.



Optimum Technology Matching® Applied

		• • • •
🔲 Si BJT	🗹 GaAs HBT	🔲 GaAs MESFET
Si Bi-CMOS	SiGe HBT	Si CMOS
InGaP/HBT	🗌 GaN HEMT	SiGe Bi-CMOS
GaAs pHEMT		



Functional Block Diagram

Package Style: QFN, 16-pin, 4x4

Features

- Typical Carrier Suppression>35dBc, Sideband Suppression>35dBc over temperature with highly linear operation
- Noise Floor better than -152dBm/Hz from 800MHz to 2200MHz
- Single 5V Power Supply

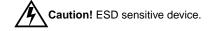
Ordering Information

RF2484 Direct Quadrature Modulator RF2484PCBA-410 Fully Assembled Evaluation Board

RF Micro Devices, Inc.	Tel (336) 664 1233
7628 Thorndike Road	Fax (336) 664 0454
Greensboro, NC 27409, USA	http://www.rfmd.com

Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	-0.5 to +7.5	V _{DC}
Input LO and RF Levels	+10	dBm
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	°C



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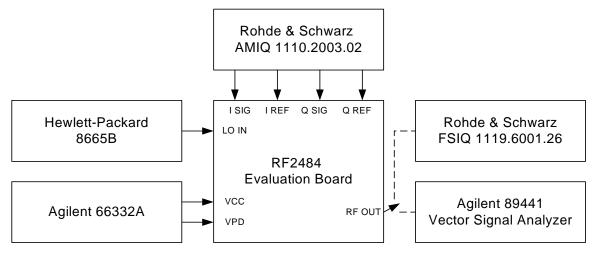
Paramotor	Specification		Unit	Condition	
Parameter	Min.	Тур.	Max.	Unit	Condition
LO Input					T=25°C, V_{CC} =5V, V_{REF} =4.1V; I and Q
-			0500		driven single-ended
Frequency Range	800		2500	MHz	
Power Level	-6	45 :05	+6	dBm	
Input Impedance		45-j95		Ω Ω	At 880MHz At 1960MHz
		52-j54 58-j50		Ω	At 2140MHz
		63-j40		Ω	At 2400MHz
Modulation Input					
Frequency Range	DC		250	MHz	
Reference Voltage (V _{REF})		4.1		V	
Input Resistance		30		kΩ	
Input Bias Current			40	μA	
RF Output (880MHz)					LO= -5dBm at 880MHz; Single sideband
CDMA Output Channel Power		-12		dBm	testing unless otherwise noted For ACPR=-72dBc; I&Q Amplitude=1.1V _{PP}
CDMA Output Channel Power		-12		UDIII	(single-ended)
CDMA ACPR		-72		dBc	Channel Power=-12dBm; see Test Setup for
				abo	detailed information
Carrier Suppression	50			dBc	T=25°C; P _{OUT} =-10dBm; optimized I,Q DC
					offsets
Carrier Suppression	35			dBc	Temperature cycled from -40°C to +85°C
over Temperature					after optimization at T=25°C; P _{OUT} =-10dBm
Sideband Suppression	50			dBc	T=25°C; P _{OUT} =-10dBm; optimized I,Q
					amplitude and phase balance
Sideband Suppression over Temperature	35			dBc	Temperature cycled from -40°C to +85°C after optimization at T=25°C; P _{OUT} =-10dBm
		4505		alDues /III =	
Broadband Noise Floor		-152.5		dBm/Hz	At 20MHz offset, 30kHz res BW, V _{CC} =5V; ISIG, QSIG, IREF, and QREF tied to V _{REF}
EVM		2.3		%	See Test Setup for detailed information
Phase Error		1		° RMS	See Test Setup for detailed information
Rho		.9993		i uno	See Test Setup for detailed information
Output Impedance		28-j72		Ω	
RF Output (1960MHz)					LO=-5dBm at 1960MHz; Single sideband
,		40			testing unless otherwise noted
PCS CDMA Output Power		-13		dBm	For ACPR=-72dBc; I&Q Amplitude=1.2V _{PP}
PCS CDMA ACPR		-72		dBc	(single-ended) Channel Power=-13dBm; see Test Setup for
		-12		UDC	detailed information
Carrier Suppression	50			dBc	T=25°C; P _{OUT} =-13dBm; optimized I,Q DC
					offsets
Carrier Suppression	35			dBc	Temperature cycled from -40°C to +85°C
over Temperature					after optimization at T=25°C; P_{OUT} =-13dBm
Sideband Suppression	50			dBc	T=25°C; P _{OUT} =-13dBm; optimized I,Q
	0.5				amplitude and phase balance
Sideband Suppression over Temperature	35			dBc	Temperature cycled from -40°C to +85°C after optimization at T=25°C; P _{OUT} =-13dBm

Demonster	Specification			11		
Parameter	Min. Typ. Ma		Max.	Unit	Condition	
RF Output (1960MHz)						
cont'd						
Broadband Noise Floor		-154.5		dBm/Hz	At 20MHz offset, 30kHz res BW, V _{CC} =5V; ISIG, QSIG, IREF, and QREF tied to V _{REF}	
EVM		2.3		%	See Test Setup for detailed information	
Phase Error		1		° RMS	See Test Setup for detailed information	
Rho		.9988			See Test Setup for detailed information	
Output Impedance		46-j22		Ω		
RF Output (2140MHz)					LO= -5dBm at 2140MHz; Single sideband testing unless otherwise noted	
W-CDMA Output Channel Power		-16		dBm	For ACPR=-60dBc; I&Q Amplitude=1.4V _{PP} (single-ended)	
W-CDMA ACPR		-60		dBc	Channel Power=-16dBm; see Test Setup for detailed information	
Carrier Suppression	50			dBc	T=25°C; P _{OUT} =-13dBm; optimized I,Q DC offsets	
Carrier Suppression over Temperature	35			dBc	Temperature cycled from -40°C to +85°C after optimization at T=25°C; P _{OUT} =-13dBm	
Sideband Suppression	50			dBc	T=25°C; P _{OUT} =-13dBm; optimized I,Q amplitude and phase balance	
Sideband Suppression over Temperature	35			dBc	Temperature cycled from -40°C to +85°C after optimization at T=25°C; P_{OUT} =-13dBm	
Broadband Noise Floor		-152		dBm/Hz	At 20MHz offset, 30kHz res BW, V _{CC} =5V; ISIG, QSIG, IREF, and QREF tied to V _{REF}	
E∨M		5.9		%	See Test Setup for detailed information	
Phase Error		2.4		° RMS	See Test Setup for detailed information	
Rho		.9961		T CIVIC	See Test Setup for detailed information	
Output Impedance		58-j16		Ω		
Power Down						
Turn On/Off Time			100	ns		
PD Input Resistance	50		100	kΩ		
Power Control "ON"			2.8	V	Threshold voltage	
Power Control "OFF"	1.0	1.2	-	V	Threshold voltage	
Power Supply					5	
Voltage		5.0		V	Specifications	
-	4.5		6.0	V	Operating Limits	
Current		66	70	mA		
			25	μΑ	Power Down	

Pin	Function	Description	Interface Schematic
1	GND	Ground connection. This pin should be connected directly to the ground plane.	
2	GND	Same as pin 1.	
3	GND	Same as pin 1.	
4	LO	The input of the phase shifting network. This pin has an internal DC blocking capacitor. This port is voltage-driven so matching at different frequencies is generally not required.	LO 0
5	GND	Same as pin 1.	
6	VCC	Power supply. An external capacitor is needed if no other low frequency bypass capacitor is nearby.	
7	PD	Power Down control. When this pin is "low," all circuits are shut off. A "low" is typically 1.2V or less at room temperature. When this pin is "high" (V_{CC}), all circuits are operating normally. If PD is below V_{CC} , output power and performance will be degraded. Operating in this region is not recommended, although it might be useful in some applications where power control is required.	PD 0
8	RF OUT	RF Output. This pin has an internal DC blocking capacitor. At some fre- quencies, external matching may be needed to optimize output power. A small amount of DC current may be present at this output. As a result, if the voltage at this pin is measured using a high impedance probe, some DC voltage may be observed at this output.	
9	GND	Same as pin 1.	
10	VCC	Same as pin 6.	
11	GND	Same as pin 1.	
12	GND	Same as pin 1.	
13	Q SIG	Baseband input to the Q mixer. This pin is DC coupled. The input drive level determines output power and linearity performance; for better car- rier suppression, sideband suppression, and dynamic range, the drive level should be as high as possible to meet the required linearity perfor- mance. The recommended DC level for this pin is 4.1V. For optimum carrier suppression, the DC voltages on I REF, Q REF, I SIG and Q SIG should be adjusted slightly to compensate for inherent undesired internal DC offsets; for optimum sideband suppression, phase and signal amplitude on IREF, Q REF, I SIG and Q SIG should be adjusted slightly to compensate for inherent undesired internal off-	
14	I SIG	 sets. See RFMD AN0001 for more detail. Baseband input to the I mixer. This pin is DC coupled. The input drive level determines output power and linearity performance; for better carrier suppression, sideband suppression, and dynamic range, the drive level should be as high as possible to meet the required linearity performance. The recommended DC level for this pin is 4.1 V; see pin 13 for more information. 	
15	I REF	Reference voltage for the I mixer. This voltage should be the same as the DC voltage supplied to the I SIG pin. A voltage of 4.1V is recom- mended; see pin 13 for more information. The SIG and REF inputs are inputs of a differential amplifier. Therefore the REF and SIG inputs are interchangeable. If swapping the I SIG and I REF pins, the Q SIG and Q REF also need to be swapped to maintain the correct phase. It is also possible to drive the SIG and REF inputs in a differential mode. This will increase the gain.	

Pin	Function	Description	Interface Schematic
16	Q REF	Reference voltage for the Q mixer. This voltage should be the same as the DC voltage supplied to the Q SIG pin. A voltage of 4.1V is recommended; see pin 13 for more information.	
Pkg Base	GND	Ground connection. The package base should be connected to the ground plane.	

CDMA/W-CDMA Test Setup



General

The above setup was used to evaluate the RF2484 under CDMA and W-CDMA modulation conditions. An AMIQ was required to provide the appropriate DC reference voltage (4.1V) for the I and Q pins. I and Q were driven single-endedly; differential drive may improve performance. A PC-controlled Rohde & Schwarz AMIQ generated the CDMA I and Q signals. In order to reduce AMIQ noise contributions to adjacent channel power, W-CDMA baseband signals were filtered using a high order low pass filter before application to the RF2484.

EVM, Phase Error, and Rho

To measure EVM, phase error, and Rho, signals were generated using the AMIQ and decoded with the Agilent VSA. For CDMA Cellular and PCS, I and Q input signals were generated with the Pilot Channel active, 32x oversampling and base station equifilters. For W-CDMA, the Common Pilot Channel was active with 8x oversampling and a root cosine filter. In all cases, relative signal amplitude levels were adjusted to optimize signal quality.

CDMA Modulation Setup (Cellular and PCS)

To measure ACPR, I and Q input signals were generated using the following settings:

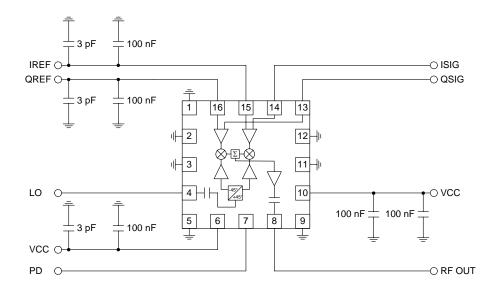
- Pilot Channel active
- Sync Channel active
- Paging Channel active
- 6 Traffic Channels active
- 32x Oversampling
- Base Station equifilter

W-CDMA Modulation Setup

To measure W-CDMA ACPR, I and Q input signals were generated using the following settings in the AMIQ:

- P-CPICH (Common Pilot Channel) active
- P-SCH (Sync Channel) active
- P-CCPCH (Primary Common Control Physical Channel) active
- P-ICH (Page Indicator Channel) Active
- DL-DPCCH (Dedicated Physical Control Channel) active
- 6 DPCH (Dedicated Physical Channels) active
- 8x Oversampling

Application Schematic



Evaluation Board Schematic

